TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT process)

2SC2670

High Frequency Amplifier Applications
AM High Frequency Amplifier Applications
AM Frequency Converter Applications

• Low noise figure: NF = 3.5dB (max) (f = 1 MHz)

Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	V _{CBO}	35	V
Collector-emitter voltage	V _{CEO}	30	V
Emitter-base voltage	V _{EBO}	4	V
Collector current	Ic	100	mA
Base current	Ι _Β	20	mA
Collector power dissipation	PC	200	mW
Junction temperature	Tj	125	°C
Storage temperature range	T _{stg}	-55~125	°C

Weight: 0.13 g (typ.)

Electrical Characteristics (Ta = 25°C)

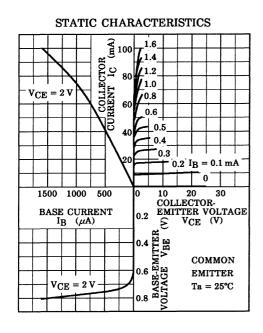
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	$V_{CB} = 35 \text{ V}, I_{E} = 0$	_	_	0.1	μА
Emitter cut-off current	I _{EBO}	V _{EB} = 4 V, I _C = 0	_	_	1.0	μА
DC current gain	h _{FE} (Note)	V _{CE} = 12 V, I _C = 2 mA	40	_	240	
Collector-emitter saturation voltage	V _{CE (sat)}	$I_C = 10 \text{ mA}, I_B = 1 \text{ mA}$	_	_	0.4	V
Base-emitter saturation voltage	V _{BE (sat)}	$I_C = 10 \text{ mA}, I_B = 1 \text{ mA}$	_	_	1.0	V
Transition frequency	f _T	V _{CE} = 10 V, I _C = 2 mA	80	_	_	MHz
Reverse transfer capacitance	C _{re}	V _{CE} = 10 V, f = 1 MHz	_	2.2	3.0	pF
Collector-base time constant	C _c .r _{bb} ,	$V_{CE} = 10 \text{ V}, I_{E} = -1 \text{ mA}, f = 30 \text{ MHz}$	_	_	50	ps
Noise figure	NF	V_{CE} = 10 V, I_{E} = -1 mA, f = 1 MHz, R_{g} = 50 Ω	_	2.0	3.5	dB

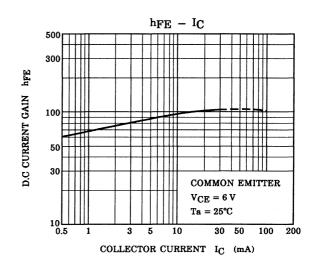
Note: hFE classification R: 40~80, O: 70~140, Y: 120~240

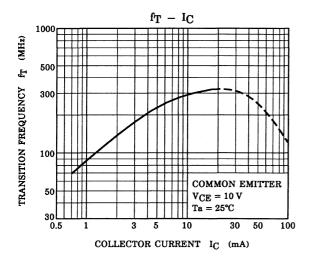
Y Parameters (typ.) (common emitter $V_{\text{CE}} = 6 \text{ V}, \, I_{\text{E}} = -1 \text{ mA}, \, f = 1 \text{ MHz})$

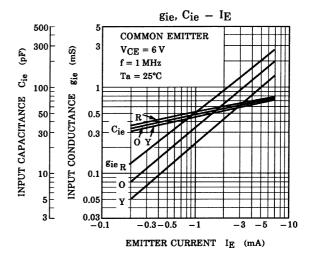
Characteristics	Symbol	2SC2670-R	2SC2670-O	2SC2670-Y	Unit
Input conductance	gie	0.5	0.35	0.22	mS
Input capacitance	C _{ie}	50	48	46	pF
Output conductance	g _{oe}	4	5	6.5	μS
Output capacitance	C _{oe}	3.7	3.4	3.2	pF
Forward transfer admittance	y _{fe}	36	36	36	mS
Phase angle of forward transfer admittance	$\theta_{\sf fe}$	-1.6	-1.6	-1.6	٥
Reverse transfer admittance	y _{re}	14	14	14	μS
Phase angle of reverse transfer admittance	$\theta_{\sf re}$	-90	-90	-90	٥

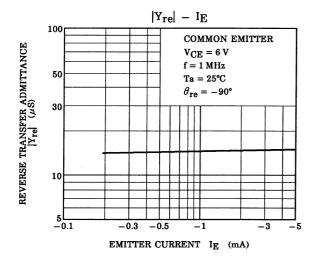
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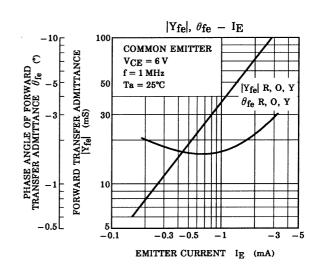




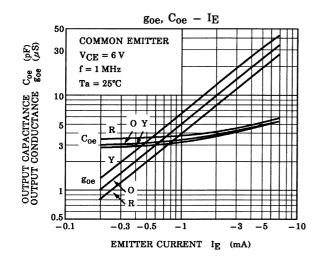


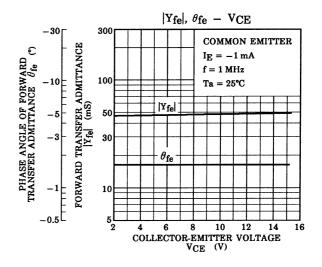


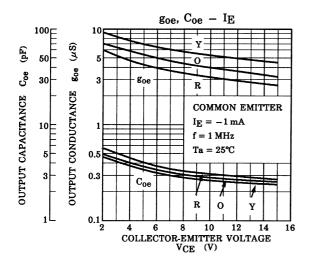


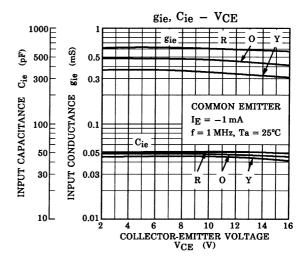


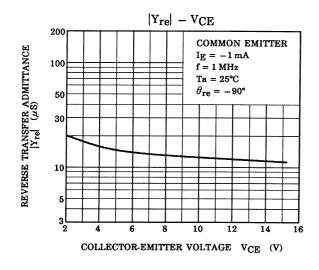
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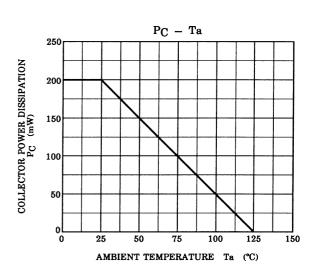












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